W-CDMA 2110 MHz to 2170 MHz fully integrated Doherty transistor AMPLEON

Product data sheet

Rev. 4 — 1 September 2015

## 1. Product profile

### 1.1 General description

The BLD6G22L-50 and BLD22LS-50 incorporate a fully integrated Doherty solution using Ampleon's state of the art GEN6 LDMOS technology. This device is perfectly suited for CDMA base station applications at frequencies from 2110 MHz to 2170 MHz. The main and peak device, input splitter and output combiner are integrated in a single package. This package consists of one gate and drain lead and two extra leads of which one is used for biasing the peak amplifier and the other is not connected. It only requires the proper input/output match and bias setting as with a normal class-AB transistor.

#### Table 1. Typical performance

RF performance at  $T_h = 25$  °C.

Mode of operation	f	V <sub>DS</sub>	P <sub>L(AV)</sub>	G <sub>p</sub>	η <sub>D</sub>	ACPR	P <sub>L(3dB)</sub>
	(MHz)	(V)	(W)	(dB)	(%)	(dBc)	(W)
W-CDMA [1][2]	2110 to 2170	28	8	14	40	-30	55

 Test signal: 2-carrier W-CDMA; test model 1; 64 DPCH; PAR = 8.3 dB at 0.01 % probability on CCDF; carrier spacing 5 MHz.

[2] I<sub>Dq</sub> = 170 mA (main); V<sub>GS(amp)peak</sub> = 0 V.

#### CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Therefore care should be taken during transport and handling.

### 1.2 Features and benefits

- Typical W-CDMA performance at frequencies from 2110 MHz to 2170 MHz:
  - Average output power = 8 W
  - Power gain = 14 dB
  - Efficiency = 40 %
- Fully optimized integrated Doherty concept:
  - integrated asymmetrical power splitter at input
  - integrated power combiner
  - peak biasing down to 0 V
  - low junction temperature
  - high efficiency

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- 100 % peak power tested for guaranteed output power capability
- Integrated ESD protection
- Good pair match (main and peak on the same chip)
- Independent control of main and peak bias
- Internally matched for ease of use
- Excellent ruggedness
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

### 1.3 Applications

 High efficiency RF power amplifiers with digital pre-distortion for W-CDMA multi carrier applications in the 2110 MHz to 2170 MHz range.

### 2. Pinning information

Pin	Description		Simplified outline	Graphic symbol
BLD6G2	2L-50 (SOT1130A)			
1	drain			_
2	gate + bias main			
3	source	<u>[1]</u>		
4	n.c.			
5	bias peak		$ \begin{array}{c c}                                    $	001aak920
BLD6G2	2LS-50 (SOT1130B)			
1	drain			
2	gate + bias main			
3	source	<u>[1]</u>		
4	n.c.		3	
5	bias peak			001aak920

[1] Connected to flange.

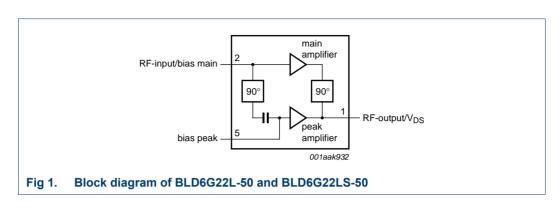
### 3. Ordering information

#### Table 3.Ordering information

Type number	Packag	Package				
	Name	Description	Version			
BLD6G22L-50	-	flanged ceramic package; 2 mounting holes; 4 leads	SOT1130A			
BLD6G22LS-50	-	earless flanged ceramic package; 4 leads	SOT1130B			

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## 4. Block diagram



### 5. Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Valid for both main and peak device.

Symbol	Parameter	Conditions	Min	Мах	Unit
V <sub>DS</sub>	drain-source voltage		-	65	V
V <sub>GS(amp)main</sub>	main amplifier gate-source voltage		-0.5	+13	V
V <sub>GS(amp)peak</sub>	peak amplifier gate-source voltage		-0.5	+13	V
I <sub>D</sub>	drain current		-	10.2	А
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		-	200	°C

## 6. Thermal characteristics

Table 5.	Thermal characteristics			
Symbol	Parameter	Conditions	Тур	Unit
R <sub>th(j-case)</sub>	thermal resistance from junction to case	$T_{case}$ = 80 °C; $P_L$ = 8 W	[ <u>1]</u> 1.9	K/W

[1] When operated with a 2-carrier (W-CDMA) modulated signal with PAR = 8.3 dB at 0.01 % probability on the CCDF.

## 7. Characteristics

#### Table 6.Characteristics

#### Valid for both main and peak device.

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	$V_{GS}$ = 0 V; I <sub>D</sub> = 0.62 mA	65	-	-	V
V <sub>GS(th)</sub>	gate-source threshold voltage	$V_{DS}$ = 10 V; I <sub>D</sub> = 31 mA	1.4	1.8	2.4	V
$V_{GSq}$	gate-source quiescent voltage	$V_{DS}$ = 28 V; $I_{D}$ = 170 mA	1.55	2.05	2.55	V
I <sub>DSS</sub>	drain leakage current	$V_{GS}$ = 0 V; $V_{DS}$ = 28 V	-	-	1.4	μA
I <sub>DSX</sub>	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	4.95	5.5	-	А

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Table 6.	Characteristics continued
Valid for h	ath main and neal davias

valid for l	valid for both main and peak device.					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>GSS</sub>	gate leakage current	$V_{GS}$ = 11 V; $V_{DS}$ = 0 V	-	-	140	nA
g <sub>fs</sub>	forward transconductance	$V_{DS}$ = 10 V; $I_{D}$ = 1.55 A	1.4	2.2	-	S
$R_{DS(on)}$	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 V;$ I <sub>D</sub> = 1.085 A	-	0.52	0.736	Ω

## 8. Application information

#### Table 7. Application information

Mode of operation: 2-carrier W-CDMA; PAR 8.3 dB at 0.01 % probability on CCDF; carrier spacing = 5 MHz; f = 2140 MHz; RF performance at  $V_{DS} = 28$  V;  $I_{Dq} = 170$  mA;  $V_{GS(amp)peak} = 0$  V;  $T_{case} = 25$  °C; unless otherwise specified; in a production circuit.

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
$P_{L(AV)}$	average output power		-	8	-	W
G <sub>p</sub>	power gain	$P_{L(AV)} = 8 W$	12.5	14	-	dB
$\eta_D$	drain efficiency	$P_{L(AV)} = 8 W$	37	40	-	%
PARO	output peak-to-average ratio	$P_{L(AV)} = 8 W$	-	7.6	-	dB
RL <sub>in</sub>	input return loss	$P_{L(AV)} = 8 W$	10	17	-	dB
ACPR	adjacent channel power ratio	$P_{L(AV)} = 8 W$	-	-30	-24	dBc

#### Table 8. Application information

Mode of operation: Pulsed CW;  $\delta = 10$  %;  $t_p = 100 \ \mu$ s; RF performance at  $V_{DS} = 28$  V;  $I_{Dq} = 170 \ m$ A;  $V_{GS(amp)peak} = 0$  V;  $T_{case} = 25 \ C$ ; unless otherwise specified; in a production circuit.

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
P <sub>L(3dB)</sub>	output power at 3 dB gain compression		46	55	-	W

#### 8.1 Ruggedness in Doherty operation

The BLD6G22L-50 and BLD6G22LS-50 are capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions:  $V_{DS} = 28 \text{ V}$ ;  $I_{Dq} = 170 \text{ mA}$ ;  $P_L = 8 \text{ W}$  (W-CDMA); f = 2140 MHz.

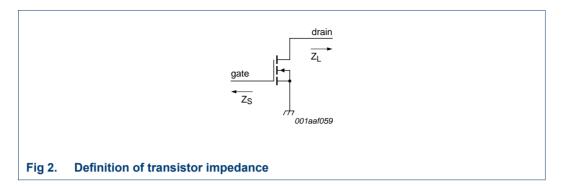
#### 8.2 Impedance information

#### Table 9. Typical impedance

Measured load-pull data; typical values unless otherwise specified.

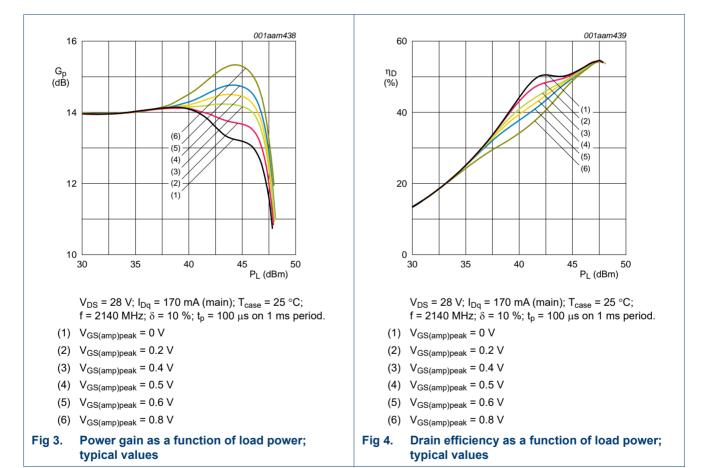
f	Z <sub>S</sub>	ZL
MHz	Ω	Ω
2050	9.4 – 12.3j	5.5 – 7.6j
2110	11.4 – 11.2j	6.7 – 8.2j
2140	12.3 – 10.5j	7.0 – 7.5j
2170	12.2 – 9.3j	7.2 – 6.8j
2230	11.8 – 7.3j	5.4 – 5.5j

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#### 8.3 Performance curves

Performance curves are measured in a BLD6G22L-50 application circuit.

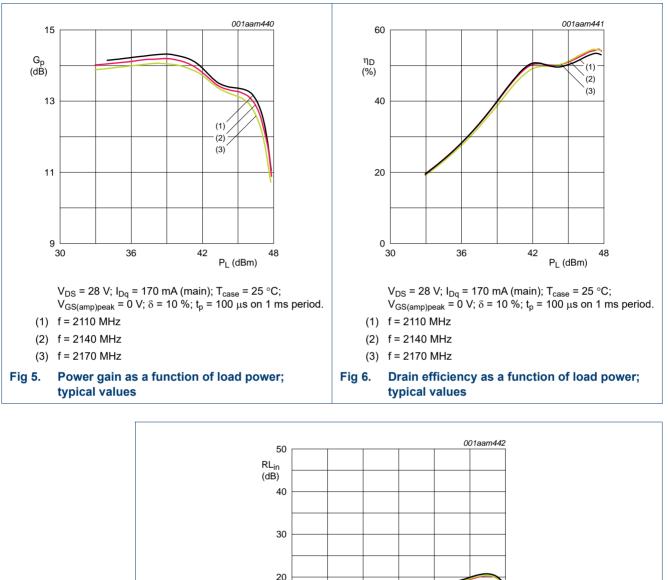


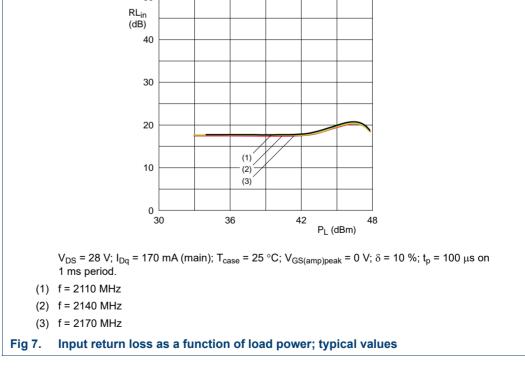
#### 8.3.1 CW pulsed

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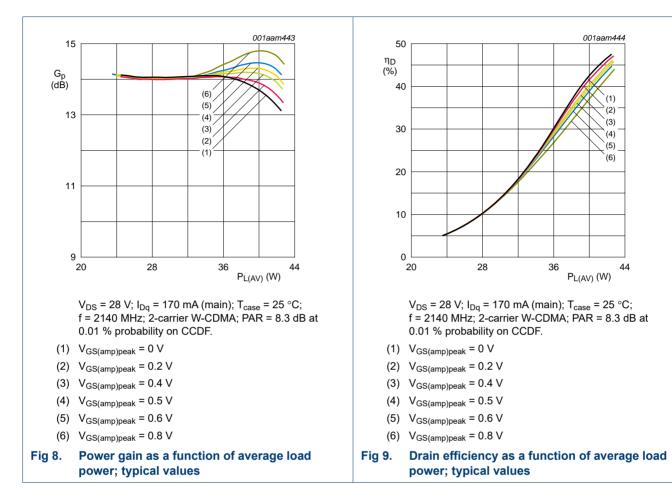


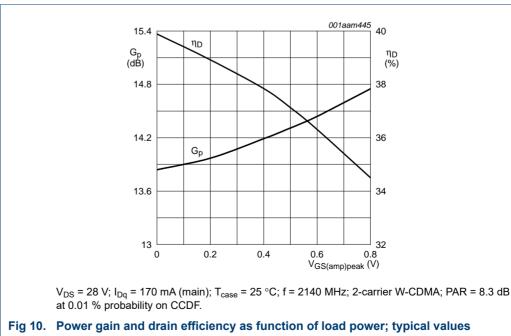
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8.3.2 W-CDMA





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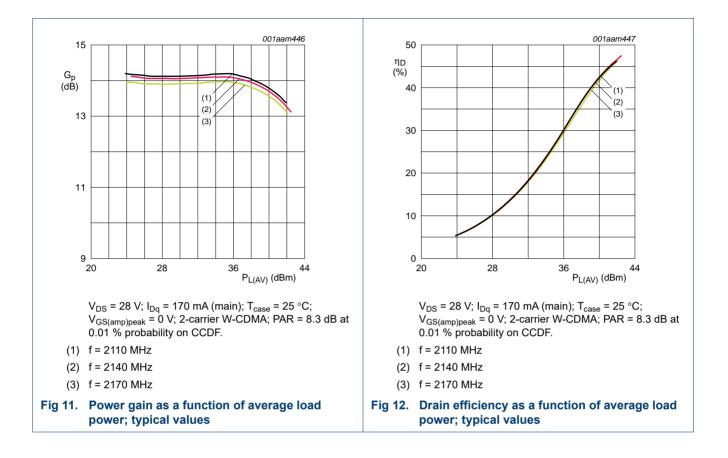
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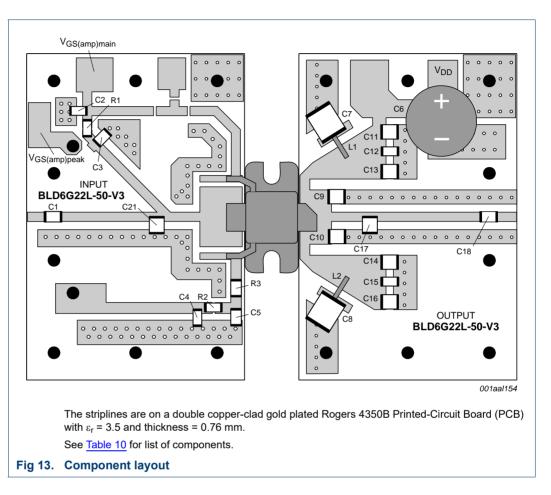
# BLD6G22L-50; BLD6G22LS-50

### W-CDMA 2110 MHz to 2170 MHz fully integrated Doherty transistor



#### W-CDMA 2110 MHz to 2170 MHz fully integrated Doherty transistor

## 9. Test information



### Table 10.List of components

#### See Figure 13 for component layout.

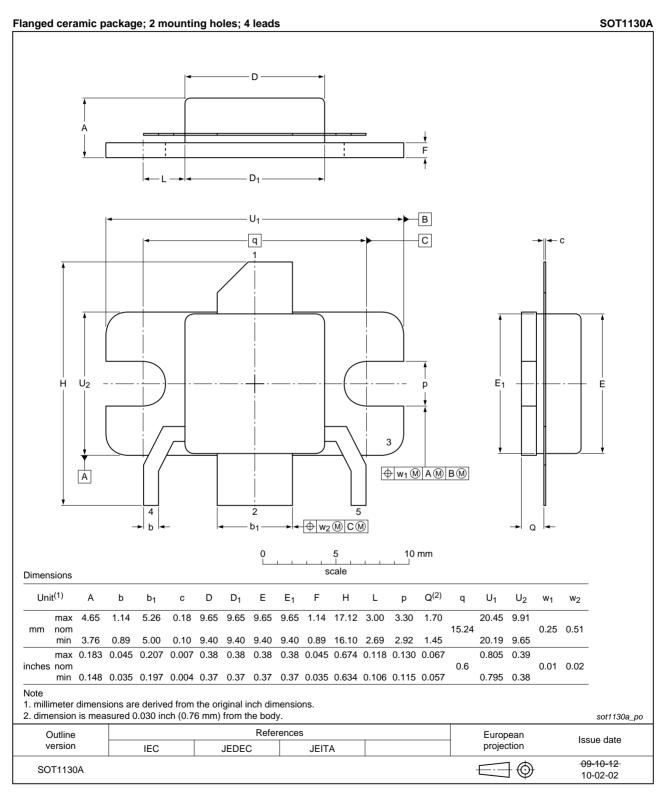
Component	Description	Value	Dimensions
C1, C3, C5, C18	multilayer ceramic chip capacitor	9.1 pF	[1]
C2, C4, C12, C15	multilayer ceramic chip capacitor	100 nF	
C6	electrolytic capacitor	470 μF; 63 V	
C7, C8	multilayer ceramic chip capacitor	10 μF	
C9, C10	multilayer ceramic chip capacitor	1.2 pF	[1]
C11, C13, C14, C16	multilayer ceramic chip capacitor	8.2 pF	[1]
C17	multilayer ceramic chip capacitor	0.8 pF	[1]
C21	multilayer ceramic chip capacitor	1.0 pF	[1]
L1, L2	copper wire	-	diameter = 0.8 mm; length = 8 mm
R1	SMD resistor	3.6 Ω	1206
R2	SMD resistor	33 Ω	1206
R3	SMD resistor	10 Ω	1206

[1] American Technical Ceramics type 100B or capacitor of same quality.

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## **10. Package outline**



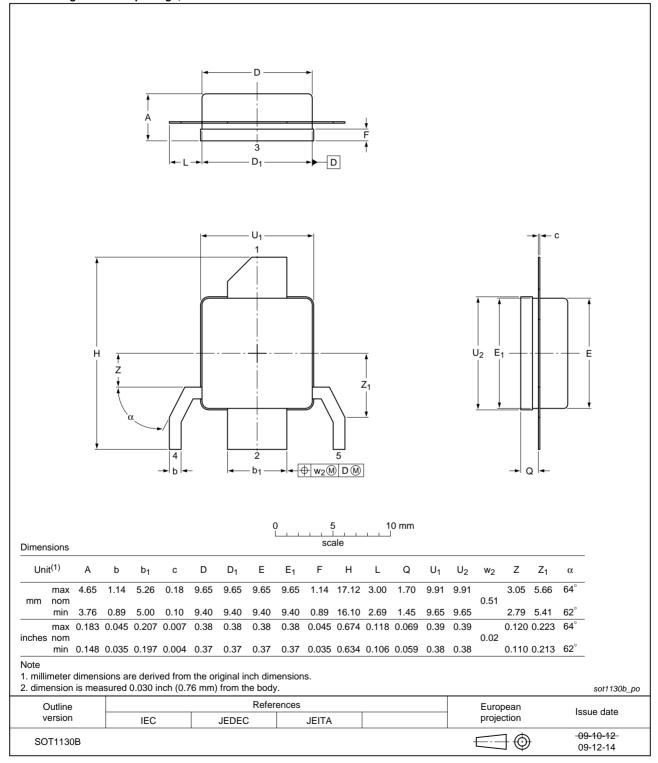
#### Fig 14. Package outline SOT1130A



### W-CDMA 2110 MHz to 2170 MHz fully integrated Doherty transistor







#### Fig 15. Package outline SOT1130B

### W-CDMA 2110 MHz to 2170 MHz fully integrated Doherty transistor

## **11. Abbreviations**

Table 11. Abbreviations			
Acronym	Description		
CCDF	Complementary Cumulative Distribution Function		
CDMA	Code Division Multiple Access		
CW	Continuous Wave		
DPCH	Dedicated Physical CHannel		
LDMOS	Laterally Diffused Metal-Oxide Semiconductor		
PAR	Peak-to-Average power Ratio		
RF	Radio Frequency		
SMD	Surface Mounted Device		
VSWR	Voltage Standing-Wave Ratio		
W-CDMA	Wideband Code Division Multiple Access		

## 12. Revision history

#### Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLD6G22L-50_BLD6G22LS-50#4	20150901	Product data sheet	-	BLD6G22L-50_ BLD6G22LS-50 v.3
Modifications:	<ul> <li>The format of this document has been redesigned to comply with the new identity guidelines of Ampleon.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>			
BLD6G22L-50_BLD6G22LS-50 v.3	20100817	Product data sheet	-	BLD6G22L-50_ BLD6G22LS-50 v.2
BLD6G22L-50_BLD6G22LS-50 v.2	20100318	Objective data sheet	-	BLD6G22L-50_ BLD6G22LS-50 v.1
BLD6G22L-50_BLD6G22LS-50 v.1	20091215	Objective data sheet	-	-

#### W-CDMA 2110 MHz to 2170 MHz fully integrated Doherty transistor

## 13. Legal information

### 13.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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**Product data sheet** 

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